Drying layer near a weakly attractive surface

A lla O leinikova, Ivan Brovchenko and Alfons Geiger Physical Chemistry, Dortmund University, 44221 Dortmund, Germany

E-m ail:

alla@heineken.chemie.uni-dortmund.de,brov@heineken.chemie.uni-dortmund.de alfons.geiger@udo.edu

Abstract. Depletion of the liquid density near a solid surface with a weak longrange uid-surface interaction was studied by computer simulations of the liquidvapor coexistence of a LJ uid con ned in slitlike pores. In a wide temperature range the liquid density decreases towards the surface without the formation of a vapor layer between the liquid and the solid surface. This evidences the absence of a drying transition up to the liquid-vapor critical point. Two contributions to the excess desorption tot were found. The rst one bulk exists at any tem perature and diverges as the bulk correlation length when approaching the liquid-vapor critical tem perature T... The second contribution ... bulk Lo originates from a microscopic drying layer near the solid boundary. At high tem peratures the thickness L_0 of the drying layer increases in accordance with the power law L_0 - $\ln (1-T/T_c)$, indicating a drying transition at T_c. The drying layer can be suppressed by strengthening the uidsurface interaction, by increasing the uid-surface interaction range or by decreasing the pore size.

PACS numbers: 05.70 Jk, 64.70 Fx, 68.08 Bc

1. Introduction

K now ledge of the liquid density pro less near weakly attractive surfaces is necessarry for the understanding of various phenomena, such as hydrophobic attraction between extended surfaces in water [1], slipping ow of liquids near a weakly attractive surface [2], conformational stability of biomolecules in aqueous solutions, etc. Experimental studies evidence a depletion of the liquid density near weakly attractive substrates [3, 4, 5, 6, 7, 8]. However, the shape of the liquid density pro less could not be derived unambigously from experimental data.

In the vast majority of practically important situations, the liquid is close to equilibrium with the vapor, i.e. close to the liquid-vapor coexistence. At the liquid-vapor coexistence curve the vapor (liquid) phase undergoes a wetting (drying) transition near the solid boundary at some temperature T_w (T_d) [9, 10, 11, 12]. Such a surface transition appears as the form ation of a macroscopically thick liquid layer in the vapor phase near a strongly attractive surface (wetting transition) or as a vapor layer in the liquid phase near a weakly attractive surface (drying transition). When crossing T_w (T_d) along the liquid-vapor coexistence curve, the liquid (vapor) layer could appear continuously (second-order or critical wetting/drying) or discontinuously (rst order wetting/drying).

Wetting transitions were extensively studied theoretically, experimentally and by computer simulations for various systems. The temperature of the wetting transition and its order were found to be strongly sensitive to the details of the uid-uid and uid-surface interaction [12]. In particular, in model systems with short-range uid-surface potential, the wetting transition can be of rst or second order, depending on the strength of the uid-surface potential [10, 13, 14]. The long-range uid-surface interaction can change drastically the character and temperature of the wetting transition. Critical wetting transitions become rst-order due to long-range uid-surface interactions [15]. The interplay between the short-range and long-range uid-surface interaction potentials can suppress critical wetting up to the liquid-vapor critical temperature [16] and produce a sequential (multiple) wetting transition [17].

A drying transition which is accompanied by the formation of a liquid-vapor interface at some distance from the substrate was observed for short-range uid-wall interactions (hard-wall [18, 19, 20], square-well [14, 21] and truncated LJ interactions [22]) in computer simulations and in density functional studies. Contradictory reports concerning the order of the drying transition in systems with short-range uid-wall interaction were discussed in [23]. A long-range uid-surface potential (e.g. via van der W aals forces) suppresses a drying transition at subcritical temperatures, which then can occur at the bulk critical temperature T_c only [15, 16, 24]. Since a long-range interaction between uids and solids is unavoidable in real systems, the formation of a macroscopic vapor layer between the liquid and the surface is in possible. Indeed, a drying transition was never observed experimentally [3, 25].

A lthough a m acroscopic vapor layer can not appear near a surface with weak long-

range attractive potential, an e ect distantly related to a drying transition could be expected in the liquid phase below $T_{\rm c}$ as the appearance of a drying layer near the surface (which is not a macroscopic vapor layer and could be considered as "embryo of drying" [26]). This drying layer can noticeably in uence the liquid density pro le near a solid surface.

Due to the necessary boundary conditions the behavior of the uid density near a planar solid substrate can only be studied by computer simulations in a pore geometry. Most of the computer simulation studies of wetting and drying transitions were performed in NVT ensembles, where slitlike pores with symmetrical or asymmetrical walls were incompletely lled (see, for example Refs.[22, 24]. In such simulations the average density of the connect uid is deeply inside the two-phase region and a correct reproduction of the liquid-vapor coexistence is questionable. Even when the liquid-vapor interface in such a pore is well established, it is formed parallel to the wall and, therefore, the wetting phase is represented in such a system as a wetting layer only. In our computer simulation studies of surface transitions we use another approach: simulations of the liquid-vapor coexistence curve of uids, conned in pores of various sizes, with subsequent extrapolation of the results to sem i-in nite systems.

The chem ical potential of the liquid-vapor phase transition of the con ned uid is shifted with respect to the bulk. This suppresses the formation of a wetting or liquid layer along the liquid-vapor coexistence of the con ned uid below and above the temperature of the wetting transition, respectively [12]. To study the possible appearance of a drying (or vapor) layer in the saturated liquid near a weakly attractive surface, we have investigated the temperature evolution of the density proles along the pore coexistence curve. The data obtained for uids in pores of various sizes and with dierent uid-surface potentials, are compared with the available theoretical predictions and experimental observations.

A LJ uid was con ned in pores of width H = 40 (is the molecular diam eter) with weakly attractive walls, which interact with the molecules of the uid via a longrange potential. The well depth of the uid-surface potential was about 70% of the well depth of the uid-uid potential. This is close to the interaction between neon atom s and a cesium substrate, the weakest known physisorption system, recently studied experimentally and by simulations [3, 25]. In our recent paper [27], the liquid-vapor coexistence curve of a LJ $\,$ uid was simulated in a smaller pore with H = 12) with the same uid-surface porential. A depletion of the liquid density near the pore wall was observed in a wide temperature range along the pore coexistence curve without any trend towards the formation of a vapor or drying layer. It was found, that the uid near the wall follows the universal power laws of the surface critical behaviour of Ising systems [28, 29]. In particular, a universal behavior of the local order parameter pro les, de ned as the di erence between the local densities $_1(z_1)$ and $_y(z_2)$ of the coexisting liquid and vapor phases at some distance z from the pore walls, was observed in a wide temperature range [27, 30, 31]. The intrusion of the surface critical behavior into the bulk uid is governed by the bulk correlation length , which diverges

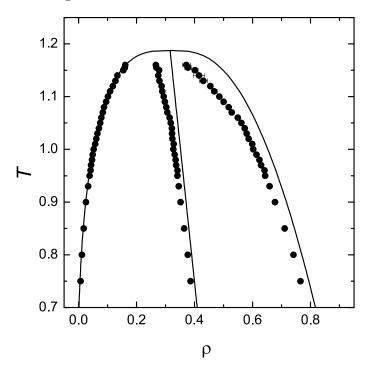


Figure 1. Coexistence curve and diam eter of the LJ uid con ned in the slitlike pore of width H=40 (circles). The bulk coexistence curve and diam eter of the LJ uid [27] are shown by solid lines.

when approaching the critical point:

$$() = _{0}$$

where = $(1 - T/T_c)$ is the reduced deviation of the tem perature T from the bulk critical tem perature T_c , = 0.63 [32] is the universal critical exponent and $_0$ is the system dependent amplitude.

In view of the high sensitivity of the surface phase transitions to small changes of the chem ical potential, the observation of a vapor or drying layer in a pore with H = 12 was, probably, prevented by the shift of the liquid-vapor phase transition in such a rather small pore. To reduce the in uence of connement and to promote the observation of a vapor or drying layer, the pore width should be as large as possible. In the present paper we approach the bulk coexistence by performing simulations in a very large pore of width H = 40. To extrapolate the results to a semin nite system the liquid-vapor coexistence of the LJ uid in several pores of intermediate sizes between H = 12 and A = 12 and A = 12 and A = 12 was simulated.

2. M ethod

Coexistence curves of a con ned LJ uid were determ ined using M onte C arb simulations in the G ibbs ensemble (GEMC) [33]. GEMC simulations allow to achieve direct equilibration of the two coexisting phases, which are simulated at a given temperature

simultaneously in two simulation cells. The details of the simulations, parameters of the model uid, as well as its bulk coexistence curve are given in our previous paper [27]. To study the behavior of the liquid near the surface, the LJ uid was con ned in a slitlike pore with structureless walls. Each wall interacts with the particles of the uid via the long-range potential of a single plane of LJ molecules:

$$U_w(z) = 4 \text{ f } 0.4 (=z)^{10} (=z)^4;$$
 (2)

where z m easures the distance to the wall and the param eter f determ ines the strength of the uid-wall interaction relatively to uid-uid interaction and is the diam eter of the LJ particles. No truncation was applied to U_w (z). In the present paper we report the results obtained for a pore of width H=40 and $U_{w1}(z)=U_w$ (z, f=0.3), which corresponds to a weakly attractive (solvophobic) surface with a well-depth of the uid-wall interaction of about 70% of the well-depth of the uid-uid interaction. To study the e ect of the pore size on the liquid density prole and the appearance of a drying layer, we also simulated the liquid-vapor coexistence and the liquid density proles at T=1.10 in pores of width H=16, 22 and 26 with the same uid-wall interaction U_w (z).

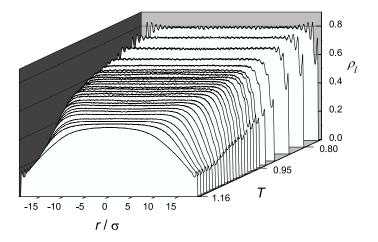
To explore the e ect of the strength of the uid-wall potential on the liquid density pro lewe also simulated the liquid-vapor coexistence in a pore with slightly stronger uid-surface interaction $U_{w2}(z) = U_w(z, f = 0.4)$. Additionally, the e ect of the range of the uid-wall interaction was explored by simulation of a system with a slower decay of the uid-wall potential $U_{w3}(z)$, which follows from an integration of the individual interactions over the half-space of LJ molecules and can be described by the equation:

$$U_{w3}(z) = 4 f (=z)^9 (=z)^3;$$
 (3)

The param eters of the potential $U_{w3}(z)$ were adjusted to get equal well depths of the potentials $U_{w3}(z)$ and $U_{w1}(z)$. This was achieved using = 0.8328 and f = 0.468 in equation (3).

The density used in the present paper is the reduced number density (scaled by 3), while T is the reduced temperature (scaled by $/k_{\rm B}$, where $k_{\rm B}$ is a Boltzmann's constant). The average density of the LJ $\,$ uid con ned in a pore was calculated taking into account the volume accessible to the $\,$ uid molecules. The $\,$ uid-wall interaction is equal to zero at the distance 0.86 $\,$ from the pore wall and so in an operational approach this interval could be divided equally between the volumes of the $\,$ uid and the solid. As a result, the volume accessible to the $\,$ uid molecules is the total pore volume L 2H reduced by a factor 1.022 for the pore of width H = 40 $\,$. A coordingly, as the distance to the pore wall $\,$ z we used the distance to the parallel plane 0.5 $\,$ inside the pore.

The density pro less of the liquid were obtained by M onte Carlo (M C) simulations in the NVT ensemble, using the average densities of the liquid phase obtained in the GEM C simulations. At high temperatures, the strong density gradient near the pore wall makes the determination of reliable density pro less in such large pores very time consuming. This problem was overcome by using two kinds of moves in M C simulations in the NVT ensemble. The rst kind of moves is a standard M C move with a maximal



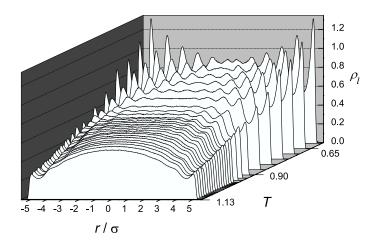


Figure 2. Temperature evolution of the liquid density pro le along the pore coexistence curves of the LJ uid con ned in a slitlike pore with H=40 (upper panel) and H=12 (lower panel).

displacement of molecule, which provides an acceptance probability of about 50%. The second kind of move is a long-distance molecular transfer inside the simulation box: an attempt to place randomly chosen uid molecule into randomly chosen position. This move is similar to the one used in GEMC simulations for molecular transfers between the two simulation boxes. Such long-distance molecular transfers essentially improve the sampling of density proles, which show a strong gradient normal to the pore wall.

3. Results

The obtained densities of the coexisting vapor ($_{v}$) and liquid ($_{1}$) phases and the diam eter (($_{1}$ + $_{v}$)/2) of the coexistence curve of the LJ uid in the slitlike pore with weakly attractive walls of width H = 40 are shown in gure 1. The critical tem perature of the pore coexistence curve is depressed due to the e ect of the con nement. It

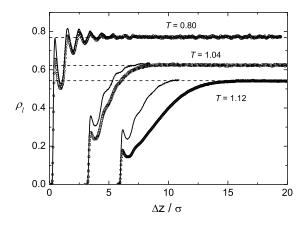


Figure 3. The density pro less of the coexisting liquid phase of the LJ uids con ned in the slitlike pores with H=40 (symbols) and 12 (solid lines). The pro less for T=1.04 and T=1.12 are shifted to larger z by 3 and 6, respectively.

is estimated as T=1.165 0.005, that is only about 0.02 below the bulk critical temperature $T_{\rm c}=1.1876$ [34, 27]. This indicates that in this case the pore coexistence curve is rather close to the coexistence curve of the bulk uid. In such a wide pore, we may therefore expect that below the pore critical temperature the properties of the uid near a wall are only slightly in uenced by the presence of the opposite wall.

Figure 1 shows that the average density of the liquid phase at the pore coexistence curve is noticeably lower than the density of the bulk LJ uid at the same temperature. This e ect becomes more pronounced at higher temperatures, i.e. at about T > 1.05and it originates from the depletion of the liquid density near a weakly attractive wall [27, 30, 31, 35, 36]. Indeed, a pronounced decrease of the liquid density near the wall is observed in the large (H = 40) as well as in the small (H = 12[27]) pore (see qure 2). At high temperatures the liquid density pro le is at in the pore interior (constant 1 (z,) in the central part of the pore) and gradually decreases toward the pore wall, displaying only a single small oscillation near the pore wall (gure 2, upper panel). Upon cooling, the region of density depletion shrinks and additional density oscillations develop gradually on the density pro les. A qualitatively similar behavior of the density prole is seen in the liquid phase in the small pore of width H = 12(gure 2, lower panel). In the small pore, however, the density depletion spreads over the whole pore near the pore critical temperature and the at part of liquid density pro le is not observed.

A direct comparison of the density pro les of the saturated liquid in the small and large pores is shown in gure 3 for some temperatures. At T=0.80 the pro les are practically identical in both pores. The density oscillations are slightly larger in the small pore. At high temperatures, the density depletion is weaker in the small pore and the dierence between $_1(z,)$ in the small and the large pore becomes more

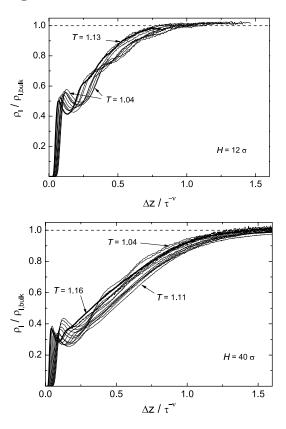


Figure 4. Scaling plot for the liquid density proles in the small pore with H=12 for T=1.04,1.05,1.06,1.07,1.08,1.09,1.10,1.11,1.12 and 1.13 (upper panel) and in the large pore with H=40 for T=1.04,1.05,1.06,1.07,1.08,1.09,1.10,1.11,1.12,1.13,1.14,1.15,1.155 and 1.16 (lower panel). The highest studied tem perature for each pore is shown by a thick solid line.

pronounced with increasing temperature.

It was shown [27, 31] that the local order param eter proles $(z_r) = (_1(z_r) - _v(z_r))/2$, in the small pore of width H = 12 with weakly attractive walls collapse into a single master curve, when the local order param eter is normalized by the bulk order param eter, and the distance to the pore wall is normalized by the bulk correlation length (see gure 9 in Ref. [27]). Such a universal behavior of (z_r) evidences that the drying transition, which is expected at the bulk critical temperature, does not in uence the liquid density proles in such a small pore. In the large pore of width H = 40, we do not obtain such universal behavior of (z_r) when using the same approach, as described above [27]. We have found, that this discrepancy originates from the quite different temperature dependences of the density proles of the liquid phase in small and large pores.

The liquid density pro less at various temperatures can be compared, using the normalized density $_1(z,)/_{l;bulk}()$, where $_{l;bulk}()$ is the liquid density of the bulk LJ uid (the values, obtained in Ref. [27], are shown in the last column of Table 1). Because the intrusion of the surface perturbation into the bulk uid is governed by the

Table 1. The values of the tting parameters , L_0 and $_{1;bu\,lk}$ in equation 6 when tted to the liquid density pro les in the large pore of width H = 40 . Uncertainties of the tting parameters correspond to the con dence level 95% . The values of $_{1;bu\,lk}^0$ were obtained by direct GEM C simulations of the liquid-vapor equilibrium [27].

T	/	L ₀ /	1;bu lk	0 l;bulk
	0.01	0.01	0.0005	1,DUIK
0.75	0.19	0.92	0.7935	0.793
0.80	0.24	0.89	0.7703	0.769
0.85	0.35	0.83	0.7424	0.743
0.90	0.56	0.84	0.7161	0.717
0.93	0.62	0.89	0.6996	0.697
0.95	0.69	0.99	0.6880	0.684
0.96	0.66	0.92	0.6826	0 . 678
0.97	0.75	1.05	0.6764	0 . 672
0.98	0 . 67	0.95	0.6649	0.665
0.99	0.81	1.14	0.6634	0.659
1.00	0.87	1.29	0.6560	0.651
1.01	0.82	1.17	0.6484	0.644
1.02	0.82	1.23	0 . 6362	0 . 637
1.03	0.89	1.31	0 . 6328	0 . 628
1.04	0.87	1.31	0 . 6247	0.622
1.05	0.95	1.40	0.6164	0.613
1.06	1.10	1.57	0.6103	0.605
1.07	1.16	1 . 73	0.5920	0.597
1.08	1.16	1.84	0.5830	0.590
1.09	1.31	1.23	0.5760	0.576
1.10	1.47	2.26	0.5630	0.568
1.11	1.57	2 . 69	0.5550	0.558
1.12	1 . 68	2.71	0.5420	0.547
1.13	1.95	2.87	0.5210	0.529
1.14	2.14	3.18	0.5140	0.524
1.15	2.40	3 <i>2</i> 8	0.5036	0.502
1.155	2.91	3 . 69	0.5065	0.495
1.16	3.32	3 . 75	0.493	0.488

bulk correlation length , it is reasonable to display the distance to the pore wall in terms of . Taking into account the universal temperature dependence of along the coexistence curve (equation (1)), we can use $\,$ z/ as a normalized distance variable. The normalized density proles of the liquid in the small and the large pore are compared

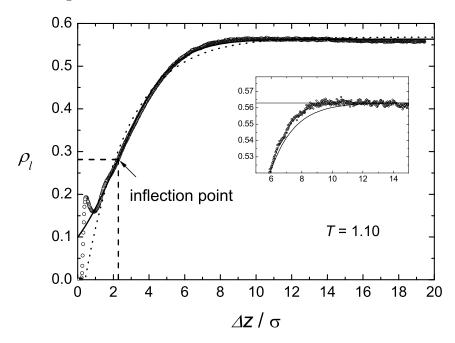


Figure 5. Liquid density pro le in the large pore with H=40 at T=1.10 (circles) and the to equation 6 with the parameters shown in Table 1 (solid line) and to equation 4 (dotted line). Coordinates of the in ection points are shown by dashed lines. The inset gives a sectoral magnication. The value $_{1;bu\,lk}$ found from the t is shown by the horizontal line in the inset.

in gure 4 in the temperature range from T = 1.04 up to the highest temperature of the two-phase coexistence in the pore.

In the small pore, the normalized density prole $_{1}(\ z,\)$ can be roughly described by the exponential equation:

$$\frac{1(z;)}{|z_{11}|_{1}(z)} = 1 \exp \frac{z l_{0}}{z} : \tag{4}$$

The values of the parameter $\frac{1}{0}$ obtained from the ts do not exceed a few tenth of , whereas the value of the tting parameter $\frac{1}{0}$ is about 0.3 , close to the value of $\frac{1}{0}$, obtained from the master curve of the order parameter process in Ref. [27]. In the large pore, the shape of the liquid density process is qualitatively dierent from that in the small pore (gure 4). Moreover, in the large pore the normalized process $\frac{1}{1}(z, z)$ of $\frac{1}{12000}$ (vary with temperature non-monotonously with the "lowest" process at z = 1.11 (see gure 4). The shape of the liquid density process at any temperature can not be tted to the exponential equation (4).

These peculiarities of the liquid density pro less in the large pore indicate the possible presence of some non-universal contribution to the surface behavior. As the increase of the pore size can be considered as an approach to a semi-in nite system, one may expect that this peculiar behavior is connected with the formation of a drying layer, caused by a drying transition at the bulk critical temperature [12]. If such a drying layer appears in a liquid phase near the surface of a large pore, the liquid density pro le

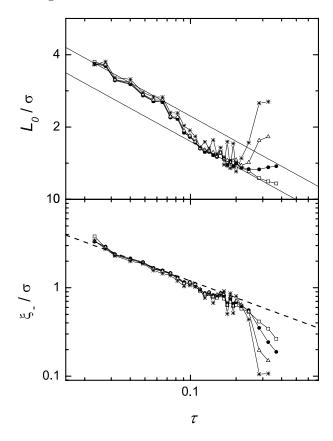


Figure 6. Temperature dependence of the thickness of the drying layer L_0 and correlation length , obtained from the ts of equation (6) to the part of the liquid density pro le $_1$ (z,), which extends from the pore center to various distances z $_{\rm cut}$ from the surface: z $_{\rm cut}$ = 0 (squares), 1 (circles), 2 (triangles) and 3 (stars). A logarithm ic behavior described by equation (7) with const = -0.05 and -0.85 is shown by upper and lower solid lines, respectively. The power law (1) with $_0$ = 0.28 is shown by a dashed line.

should be described by an interface-like equation. The density pro le at the intrinsic liquid-vapor interface, derived from the van der W aals theory, could be described by the following equation [37, 38]:

$$_{1}(z;) = \frac{_{1;\text{bulk}}() \quad _{\text{v;bulk}}()}{2} \tanh \quad \frac{z \quad L_{0}}{2} + \frac{_{1;\text{bulk}}() + _{\text{v;bulk}}()}{2}; \tag{5}$$

where L_0 is the distance from the liquid-vapor interface to the solid surface. This intrinsic interfacial prole can be a ected by capillary waves, i.e. them all uctuations of the interface [39]. Far from the critical point the bulk uctuations are small and capillary waves are the dominant factor, which determ ines the thickness of the interface [40]. Upon rising the temperature the density uctuations in the bulk phases become more important, yielding an intrinsic interfacial thickness proportional to the increasing bulk correlation length, as described by equation (5). Since the expected interface is close to the wall, the capillary waves can be suppressed by a long-range uid-surface interaction.

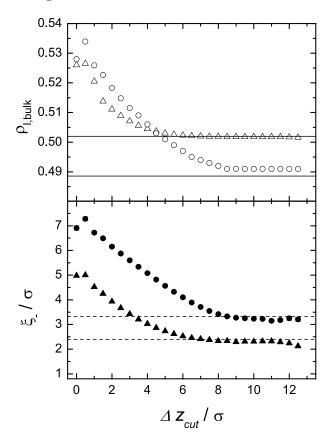


Figure 7. Variation of the thing parameters $_{1;bu\,lk}$ and at T = 1.15 (triangles) and T = 1.16 (circles), when equation (4) is the to those parts of the liquid density pro le $_1$ (z,), which extend from the pore center to various distances z $_{cut}$ from the surface. The values of the liquid density at the bulk coexistence curve are shown by solid lines (upper panel). The values of the bulk correlation length $_1$, obtained from the tof equation (6) to $_1$ (z,) (Table 1) are shown by dashed lines (lower panel).

We have found, that the liquid density probe in the large pore can be described by equation (5) at low temperatures, when the density of the bulk vapor is close to zero. However, equation (5) fails to the liquid density probes at high temperatures, because the value of the density near the pore wall is even lower than the bulk vapor density at the same temperature. This result is consistent with the theoretical expectations, that a vapor layer never appears near a surface with long-range uid-surface interaction [15, 16]. So, it is more reasonable to suggest not a vapor but a drying layer near the surface. Since the density distribution in a drying layer is unknown, we tted the liquid density probes to equation (5) with $_{v \neq ulk}$ as a free parameter. Such an approach provides a satisfactory description of the simulated probes apart from the rst layer of about width, where a density oscillation, caused by uid-surface interaction potential, is noticeable even at supercritical temperatures. The values of obtained from the ts were found close to zero for all studied temperatures. An example of such a twith = 0 for T = 1.10 is shown in gure 5. So, we propose the following equation to describe

the liquid density pro le $_1$ (z,) near a weakly attractive surface:

$$_{1}(z;) = \frac{_{1;\text{bulk}}()}{2} \tanh \frac{z L_{0}}{2} + 1 :$$
 (6)

There are three parameters in equation (6): L_0 , the distance of the in ection point of the such de ned liquid-drying layer interface from the surface (thickness of the drying layer), , the bulk correlation length at the liquid-vapor coexistence curve and $l_{\rm litulk}$ (), the density of the bulk liquid. The rst density oscillation (which extends over about 1 near the surface) is caused by the localization of the molecules in the well of the uid-wall potential. Since it strongly deviates from the smooth density pro le outside the rst layer, it is reasonable to exclude the rst layer from the ts. The values of the parameters obtained from the ts of equation (6) to the simulated liquid density pro les are shown in Table 1.

The tem perature dependences of the correlation length and of the thickness of the drying layer L_0 , obtained from these ts, are shown in gure 6 (solid circles). The correlation length shows a tem perature dependence, which is rather close to the simple power law described by equation (1) with an amplitude $_0=0.28$ (gure 6, lower panel, dashed line). Such an amplitude of the correlation length agrees well with the value $_0=0.3$, obtained previously from the master curve of the order parameter of a LJ uid in a narrow pore [27].

A nother estimate of the amplitude of the correlation length can be obtained based on the exponential decay of the perturbation caused by the surface: far from the surface the deviation of the local density from the bulk value is governed by the bulk correlation length and should follow equation (4). Thus, the progressive exclusion of an increasing part of the density pro lenear the surface from the t, should show a convergence of the tting parameters, including. The values of obtained from ts of equation (4) to liquid density pro les, which extend from the pore center to various distances from the surface z_{cut} are shown in gure 7 (lower panel) for two temperatures. A clear convergence of the tted values—is observed, when the tted part of the density pro—le does not approach the pore wall closer than 6—at T=1.15 and 8—at T=1.16. These converged values of—are remarkably close to the values of—obtained from the t of the data to equation (6), shown by dashed lines (gure 7).

The values $_{l
endown like}$ obtained from ts of $_1$ (z,) to the interfacial equation (6) (Table 1) are almost equal to the liquid densities in the pore center, obtained by ts of the data near the pore center to the exponential equation (4) (see solid lines in gure 7). The values $_{l
endown like}$ obtained from these ts agree very well with the bulk liquid densities obtained by direct G libbs ensimble M C simulations of the liquid-vapor equilibrium [27], which are also presented in Table 1.

Next, we test the sensitivity of the thing parameters in the interfacial equation (6) from the portion of the liquid density pro leused for the ts. For this purposes we the equation (6) to the part of $_{1}(\ z_{r})$, which extends from the pore center to some distances $z_{\rm cut}$ from the surface. The thing parameter $_{1;\rm bulk}$ was found practically independent on the choice of the thing interval. The values of the correlation length

, obtained from the ts, depend on the choice of $z_{\rm cut}$ (from 0 to 3) only at T 0.90 (see gure 6, lower panel) due to the strong density oscillations near the surface at low temperatures. At T > 0.90 the tting results for the correlation length are not sensitive to $z_{\rm cut}$.

The change of the thickness of the drying layer L_0 with temperature is shown in the upper panel of gure 6. At the lowest temperatures (T = 0.90) the tted value of L_0 is determined by the choice of $z_{\rm cut}$, namely L_0 = $z_{\rm cut}$. This correlation is clearly imposed by the strong density oscillations near the surface. Thus, if the thickness of a drying layer does not exceed 1 , meaningful value of L_0 can not be determined from the ts. At higher temperatures, L_0 does not depend noticeably on the choice of $z_{\rm cut}$. Two temperature regions could be distinguished in the temperature dependence of L_0 at T > 0.90. In the temperature interval from T = 1.11 to 1.16 the thickness of a drying layer L_0 clearly follows the logarithm ic dependence:

$$L_0 = \ln^{-1} + const \tag{7}$$

with const -0.05 (see Fig.6, upper panel, upper solid line). A quite similar logarithm ic temperature dependence of L_0 is observed in the low temperature interval from T=0.85 to 1.06, but with another value const -0.85. There is a crossover between two kinds of logarithm ic behavior in the temperature interval from T=1.07 to 1.10. Note, that the observed logarithm ic temperature dependence of L_0 is similar to that predicted for the divergence of the thickness of the wetting layer in the case of a critical wetting transition [12].

So, equation 6 allows the description of the liquid density pro les in a wide tem perature range using two properties of the bulk uid ($_{\rm l;tulk}$ and) and the thickness of the drying layer L_0 . The degree of the universality of the liquid density pro les can be illustrated by a master curve, which is essentially in proved in comparison with gure 4, where the presence of a drying layer was neglected. Now, we introduce a normalized length scale, which is measured from the liquid-drying layer interface, as ($z-L_0)/$. Using the tting parameters L_0 and $_{\rm l;tulk}$ from Table 1, the liquid density pro les collapse on a single master curve in a wide temperature range $1.04 < T < T_{\rm c}$ (see gure 8). The dashed line in gure 8 represents the interfacial equation (6) in normalized coordinates. This means, that equation (6) allows a perfect description of the liquid density pro les in the whole temperature range, where the drying layer can be clearly detected. In the temperature range above T=1.11, where the thickness of the drying layer follow equation (7) (see gure 6), $_1(\ z_r)$ can be predicted if the bulk density, the bulk correlation length and the const in equation (7) is known. Note, that the latter value can be estimated from a single density pro le.

We also test the possibility to describe the density proles of the liquid in the small pore with H=12 by the interfacial equation (6). The obtained thing values of L_0 are about 1 in the whole temperature range (gure 9). The thing values of L_0 in the small and large pores coincide at low temperatures (T < 0.90), where they are strongly in uenced by the density oscillations and, therefore, are meaningless. As far

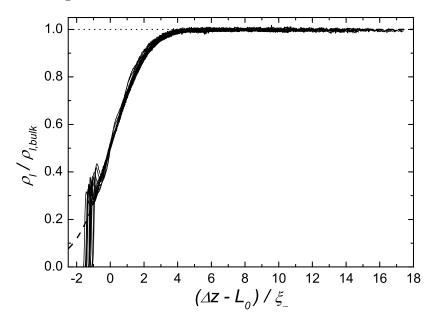


Figure 8. Scaling plot of the liquid density pro les $_1(z,)$ in the large pore H=40 for the same temperatures as in gure 4. The parameters $_{l;bu\,lk}$ and L_0 were obtained from ts of equation (7) to density pro les $_1(z,)$, which were cut at the distance 1 from the surface (Table 1). For T=1.16 the value $_{l;bu\,lk}$ from the bulk coexistence curve was used.

as a thickness of the drying layer below 1 can not be detected from the ts, the real thickness of the drying layer can be essentially lower. Thus, the tting values of L_0 for the small pore with H=12, shown in gure 9, can not be considered as an indication of a drying layer in this pore even near the pore critical temperature. Obviously, the uid layer near the surface, highly localized in the well of a uid-wall potential, can not be considered as a drying layer. This observation agrees with a previous analysis of the local order parameter in the same pore [27], which indicated the absence of a drying layer.

The values of found from the ts of $_1$ (z,) in the small pore with equation (6) are noticeably smaller than obtained from the ts of the order parameter in the same pore [27] and in the large pore (gure 9). So, the liquid density pro les in the small pore can not be described correctly by equation (6): the excitive thickness of the drying layer is ultimately overestimated in such a pore, resulting consequently in an underestimation of the value of the correlation length.

The drying layer, clearly seen in a large pore with H=40, disappears in a small pore with H=12 and the same uid-surface potential. This agrees with the theoretical expectation of strong sensitivity of the thickness of the drying layer to the chemical potential, which is shifted due to the con nement in the pore [12]. One may expect, that the thickness of a drying layer L_0 should continuously increase with increasing pore size and achieve some saturation value $L_{0;\inf}$ in a semi-in nite system. To check this expectation we have simulated liquid-vapor coexistence of the LJ uid in several

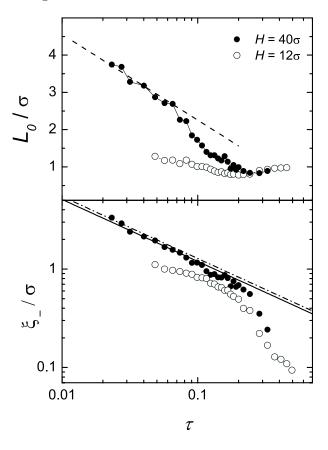


Figure 9. Tem perature dependence of the thickness of the drying layer L_0 and of the correlation length , obtained from ts of the liquid density pro les $_1$ (z,) cut at the distance 1 from the surface for large (solid circles) and small (open circles) pores. Solid and dot-dashed lines represents equation (1) with $_0$ = 0.28 (this paper) and $_0$ = 0.30 [27], respectively. Dashed line corresponds to equation (7) with const = -0.05 .

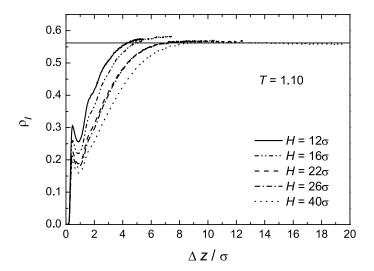


Figure 10. Liquid density pro les $_1(z,)$ at T=1.10 in pores of various width with identical uid-surface interaction potential, described by equation (2). The liquid density of the bulk uid is shown by a horizontal line.

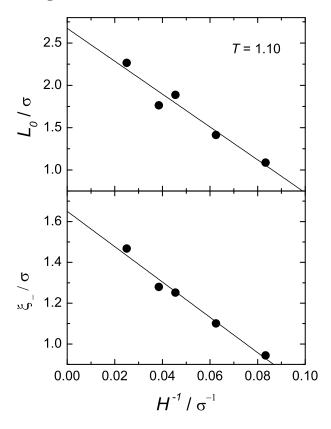


Figure 11. Dependence of the thickness of the drying layer L_0 and the correlation length , obtained from ts of the liquid density pro le $_1$ (z,) with equation (6), on the inverse pore width 1/H (circles). Linear ts of the data are shown by lines.

pores of various sizes with the sam e uid-surface interaction potential at T = 1.10. The obtained liquid density pro les shown in qure 10 indicate, that the density depletion becomes more pronounced in larger pores. The ts of $_{1}(z,)$ with equation (6) allow an estimation of the parameters L_0 and in all studied pores, and their dependences on the pore size are presented in qure 11. Note, that at this tem perature, L_0 exceeds 1 and the drying layer is indeed detectable in all pores except the sm allest one with H = 12. As the shift of the chemical potential of the phase transition in a pore relatively to a sem i-in nite system is proportional to 1/H [41], it is reasonable to consider the dependence of L₀ and on 1/H.B oth param eters show essentially a linear dependence (see gure 11). Extrapolation of these linear dependences to sem i-in nite system (1/H ! 0) gives the values: $L_{0;inf} = (2.67)$ 0.15) and $_{inf} = (1.65 \quad 0.04)$. A ssum ing that a drying layer e ectively decreases the pore size to H -2 L_0 , the dependences shown in gure 11 become non-linear and their extrapolation to sem i-in nite systems by second-order polynomial tgives $L_{0;inf} = (2.79 \quad 0.47)$ and $l_{inf} = (1.73)$. The values of , extrapolated to a sem i-in nite system, correspond to an amplitude of the correlation length $_0$ 0.32-0.33 . This value is about 15 % higher the value $_0$ = 0.28 obtained in the pore with H = 40.

Finally, we have tested the general theoretical expectation, that the formation

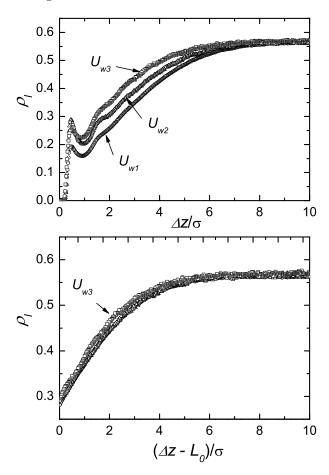


Figure 12. Upper panel: liquid density pro les $_1(z, t)$ at t = 1.10 (circles) in pores of width t = 40 with t = 40 with

of a drying layer could be suppressed by a strengthening uid-surface interaction or by extending its attractive range. For this purpose we have simulated liquid-vapor coexistence and density pro less of the coexisting phases in the large pores (H = 40) at T = 1.05, 1.10 and 1.15 with stronger interaction potential U $_{\rm w2}$ (z) and with the slower decaying potential U $_{\rm w3}$ (z) (see section M ethods for m ore details). The obtained density pro less at T = 1.10 are compared in gure 12. Evidently, the drying layer is strongly in uenced by the interaction potential. Namely, strengthening of the uid-surface potential by about 33 % causes a shrinking of a drying layer at T = 1.10 from 2.26 to 1.76 , i.e. by about 20 % . At T = 1.05 the excitive thickness of the drying layer is suppressed to about 1 . An extension of the attractive range of the uid-surface potential from r 4 to r 3 has an even stronger e ect: the drying layer almost dissappears (L0 < 1.4 at T = 1.10).

Starting from the in ection point, the shape of the liquid density pro les remains highly universal for all considered uid-surface potentials, as it is determined mainly by the bulk correlation length (see lower panel in gure 12). Note, that the details of the

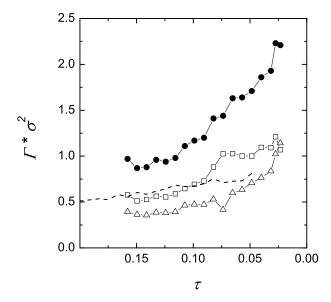


Figure 13. Tem perature dependence of the excess desorption of the liquid in the large pore: total excess desorption $_{\rm tot}$ (solid circles) and its contributions due to drying layer $_{\rm L}$ (squares) and due to increase of the correlation length (triangles). Total desorption in the small pore is shown by dashed line.

long-range attractive tail of a uid-surface potential can produce some m inor deviations of $_{1}(z_{1})$ from the universal shape, described by equation (6). An example of such deviations is also shown in the inset of gure 5.

U sing the obtained density pro les of the liquid, we analyzed the surface excess desorption, which describes a decit of mass per unit surface area caused by depletion of the liquid density near the surface. The total excess desorption $_{\rm tot}$ contains two contributions: desorption due to the presence of a drying layer $_{\rm L}$ and desorption due to the density depletion $_{\rm L}$, governed by the correlation length. We calculated these two contributions by numerical integration of $_{\rm L}$ (z,) from the surface to the in ection point $_{\rm L}$ and from the in ection point to the pore center $_{\rm L}$. The total excess desorption $_{\rm tot}$ and its two contributions are shown in gure 13 as functions of the reduced temperature. For a sem i-in nite system the excess desorption can be simply calculated by integration of equation 6 for the liquid-drying layer interface from the in ection point to in nity:

$$() = \lim_{k \to 1} \ln 2$$
: (8)

This part of the total desorption behaves like at any temperature and strongly diverges when approaching the critical point. Neglecting the density oscillations near the surface, the contribution $_{\rm L}$ can be obtained in a similar way using integration of equation 6 for the liquid-drying layer interface from the pore wall to the in ection point:

We analyzed the ability of equations (8) and (9) to describe the simulation results of the excess description. The excess description depends on the bulk uid properties

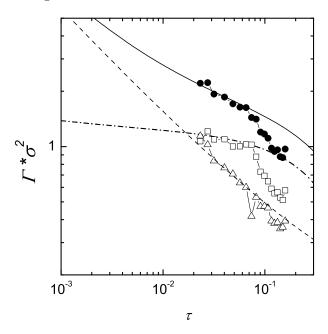


Figure 14. Tem perature dependence of the excess desorption of the liquid in double logarithm ic scale: symbols are the same as in gure 14. Desorption and $_{\rm L}$ described by equations 8 and 9 and $_{\rm tot}$ = $_{\rm L}$ are shown by dashed, dashed-dot and solid lines, respectively.

only. Knowing the temperature behavior of the bulk liquid density $_{\rm l;bulk}$ along the coexistence curve [27] and using the asymptotic equation (1) for the bulk correlation length with amplitude $_0=0.28$, we can directly obtain the temperature dependence of from equation (8) (dashed line in gure 14). Good agreement of the simulated values of with equation (8) is observed in the whole studied temperature range. Deviations at low and high temperatures should be attributed to deviations of the correlation length from the asymptotic equation (1) (see gure 6).

The excess description $_{\rm L}$, described by equation (9), apart from the bulk parameters $_{\rm Lbulk}$ and contains also the parameter ${\rm L_0}$, determined by the uid-surface interaction. We obtain meaningful estimates of ${\rm L_0}$ for the temperatures, where the thickness of the drying layer ${\rm L_0}$ exceeds about 1 . In this range ${\rm L_0}$ follows equation 7 (see gure 6) and therefore the contribution $_{\rm L}$ varies roughly as ${\rm ln}\,(^{-1})\,(_{\rm Lbulk})/2$, i.e. shows logarithm is divergence when approaching ${\rm T_c}$. The excess description $_{\rm L}$ described by equations 9, and the total excess description $_{\rm tot}$ = $_{\rm L}$, described by equations 8 and 9, are shown in gure 14 by dot-dashed and solid lines, respectively. O bviously, good agreement of the simulated values of $_{\rm L}$ with equation (9) is observed in the range, where the temperature of ${\rm L_0}$ is known.

In a wide tem perature range the contribution from the drying layer to the excess desorption is dom inant (gure 13). However, the contributions $_{\rm L}$ and approach each other with increasing tem perature and practically coincide at 0.02 (gure 14). The contribution obviously should dom inate $_{\rm L}$ at higher tem peratures, as the form er

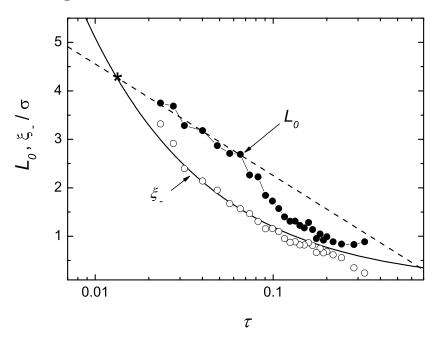


Figure 15. Tem perature dependence of the thickness of the drying layer L_0 (solid circles) and correlation length (open circles), obtained from its of the liquid density pro le $_1$ (z,), which extend from the pore center to the distance 1 from the surface. The logarithm ic law described by equation (7) with const = -0.05 is shown by dashed line. The power law (1) with $_0$ = 0.28 is shown by solid line. The tem perature, where L_0 is marked by a star.

diverges as , whereas the latter diverges logarithm ically only.

4. Discussion

We have studied the tem perature evolution of the density proles of a liquid along the liquid-vapor coexistence curve near a weakly attractive surface. To approach the uid behavior in a sem i-in nite system, the liquid-vapor coexistence curve of a LJ uid was simulated in an extremely large slitlike pore with H=40. Additionally, at some tem peratures we simulated the liquid-vapor coexistence in pores of various sizes. Strong depletion of the liquid density near a weakly-attractive pore wall is observed. The shape of the liquid density proles evidences the formation of a drying (not a vapor) layer near the pore wall with increasing temperature. This drying layer can be detected at T>1.0 (<0.15), when the distance between the injection point of the density prole and the pore wall exceeds at least one molecular diameter. We propose to describe the liquid density proles near weakly attractive surfaces by equation (6), which assumes an interface between the liquid phase and the drying layer and allows estimation of the bulk correlation length and the thickness of the drying layer L_0 .

The ts of $_1$ (z,) with the interfacial-like equation (6) and with the exponential equation (4) which describes the decay to the bulk density far from the surface, give similar values of the amplitude of the correlation length $_0$ 0.28. This evidences a

self-consistency of the proposed treatment of the liquid density prole and also indicates a negligible elect of the capillary waves on the studied interface between the liquid and the drying layer. This conclusion corroborates general theoretical arguments, concerning the in uence of a long-range uid-surface potential on the interface between vapor and wetting layer [12].

The thickness of the drying layer L_0 follows a logarithm ic temperature dependence (7), starting from T = 1.1 (i.e., at < 0.07). Such a logarithm ic divergence with approaching wetting (drying) temperature is expected for critical wetting (drying) [12]. This result is consistent with the existence of a second-order drying transition at the bulk critical temperature for long-range uid-surface interactions [15] and with experimental evidences for the absence of a drying transition at subcritical temperatures even in a system with extremely weak uid-surface interaction [3, 25], similar to the one, used in our studies. Additionally, we have shown how the thickness L_0 of the drying layer can be strongly suppressed by strengthening of the uid-surface interaction, extension of its attractive range and by connement.

In the temperature range of our simulation studies, the correlation length not exceed the thickness of the drying layer L_0 (see Table 1 and gure 15). Since the divergence of the correlation length is much stronger than the logarithm ic divergence of L_0 , when approaching the critical point should exceed L_0 . At the characteristic tem perature 0.01, shown by a star in gure 8, L_0 . Above this tem perature the interface between liquid and drying layer approaches the surface in terms of correlation length. The e ective "thickness" of the total region of density depletion near the surface should diverge asymptotically as the correlation length. This corroborates the theoretical expectations for the thickness of the wetting (drying) layer, when the critical wetting (drying) transition occurs at the bulk critical temperature [16]. Experiments with uid mixtures indicate, that the partial wetting layer decays exponentially with distance from the surface and itse ective "thickness" is proportional to the bulk correlation length [42, 43].

W e found that the total excess desorption due to the depletion of the liquid density near a weakly attractive surface should diverge as the bulk correlation length

= 0:63 when approaching the critical tem perature. This strong divergence, described by equation (8), originates from that part of the liquid density pro le which extends from the bulk liquid to the in ection point of the liquid-drying layer interface. Slight variations of the uid-surface potential do not a ect noticeably this part of the pro les (see gure 12, lower panel) and, accordingly, the value of , whereas the thickness of the drying layer is highly sensitive to the details of the uid-surface potential (gure 12, upper panel).

The observed divergence of the excess description is stronger than $=^{0.305}$, expected from the theory of critical adsorption [44]. We do not see the possibility of a crossover of to the power law of critical adsorption with further approaching the critical temperature, as the in ection point of the liquid-drying layer interface asymptotically approaches the value $_{\rm c}/2$. Such a crossover could be possible only if the

drying layer transforms into a vapor layer and, accordingly, the density at the in ection point of the liquid-vapor interface approaches $_{\rm c}$ with increasing tem perature. However, this scenario is forbidden for systems with long-range uid-surface interaction, where vapor layer do not appears below the critical tem perature [15, 16, 24]. Note, that recent experimental studies of the adsorption in binary mixtures indicate, that at subcritical tem peratures diverges stronger than [43, 45]. Such behavior may have the same origin, as that observed in our computer simulations.

5. References

- [1] Christenson H K and Claesson P M 2001 Adv. Coll. Inter. Sci. 91 391
- [2] Vinogradova O I 1999 Int. J. Miner. Process 56 31
- [3] Hess G B, Sabatini M J and Chan M H W 1997 Phys. Rev. Lett. 78 1739
- [4] Doerr A K, Tolan M, Seydel T and Press W 1998 Physica B 248 263; Doerr A K, Tolan M, Schlom ka J-P and Press W 2000 Europhys. Lett. 52 330
- [5] Steitz R, Gutberlet T, Hauss T, Klosgen B, Krastev R, Schemmel S, Simonsen A C and Findenegg GH 2003 Langmuir 19 2409
- [6] Jensen T R, Jensen M O, Reitzel N, Balashev K, Peters G H, K jaer K and B jornholm T 2003 Phys. Rev, Lett. 90 086101
- [7] Lakshm inarayanan V and Sur U K 2003 Pram ana J. Phys. 61 1739
- [8] SchwendelD, HayashiT, DahintR, Pertsin A, GrunzeM, StreitzR and SchreiberF 2003 Langmuir 19 2284
- [9] Cahn JW 1977 J. Chem . Phys. 66 3667.
- [10] Nakanishi H and Fisher M E 1982 Phys. Rev. Lett. 49 1565
- [11] Pandit R, Schick M and Wortis M 1982 Phys. Rev. B 26 5112
- [12] Dietrich S 1988 Phase Transitions and Critical Phenomena vol 1 ed C Domb and J L Lebowitz (New York: A cademic/New York) p 1
- [13] Binder K and Landau D P 1988 Phys. Rev. B 37 1745
- [14] SwolF and Henderson JR 1989 Phys. Rev. A 40 2567
- [15] Ebner C and Saam W F 1987 Phys. Rev. B 35 1822; 1987 Phys. Rev. Lett. 58 587
- [16] Nightingale M P and Indekeu JO 1985 Phys. Rev. B 32 3364
- [17] Shahidzadeh N, Bonn D, Ragil K, Broseta D and Meunier J 1998 Phys. Rev. Lett. 80 3992
- [18] Henderson JR and van SwolF 1985 Mol. Phys 56 1313
- [19] Evans R, Roth R and Bryk P 2003 Europhys. Lett. 62 815
- [20] Stewart M C and Evans R 2005 Phys. Rev. E 71 011602
- [21] Swolf and Henderson JR 1991 Phys. Rev. A 43 2932
- [22] Nijn eijer M J P, B ruin C, Bakker A F and van Leeuwen J M J 1991 Phys. Rev. B 44 834
- [23] Henderson JR, Tarazona P, van Swolf and Valasco E 1992 J. Chem. Phys. 96 4633
- [24] Nijmeijer M JP, Bruin C, Bakker A F and van Leeuwen JM J1992 J.Phys.: Cond Matt. 4 15
- [25] Ancilotto F, Curtarolo S, Toigo F and Cole M W 2001 Phys. Rev. Lett. 87 206103
- [26] Dietrich S 2001 private communication
- [27] Brovchenko I, Geiger A and Oleinikova A 2005 Eur Phys. J. B 44 345
- [28] Binder K 1983 Phase Transitions and Critical Phenomena vol 8 ed C Domb and J L Lebowitz (London: A cademic Press/London) p 1
- [29] DiehlH W 1994 Ber. Bunsenges. Phys. Chem . 98 466; 1994 Phys. Rev. B 49 2846
- [30] Brovchenko I, Geiger A and Oleinikova A 2004 J. Phys.: Cond. Matt. 16 S5345
- [31] Brovchenko I and O leinikova A 2005 Handbook on Theoretical and Computational Nanotechnology Chapter 62 ed M Rieth and W Schommers (American Scientic Publishers) (in press)
- [32] Guida R and Zinn-Justin J 1998 J. Phys. A: Math. Gen. 31 8103

- [33] Panagiotopoulos A Z 1987 M ol. Phys. 62 701
- [34] W ilding N B 1995 Phys. Rev. E 52 602
- [35] Brovchenko I, Geiger A, Oleinikova A and Paschek D 2003 Eur. Phys. J. E 12 69
- [36] Brovchenko I, Geiger A and Oleinikova A 2004 J. Chem. Phys. 120 1958
- [37] van der W aals J D 1894 Z. Pys. Chem ., Stoechiom . Verwandtschaftsl. 13 657
- [38] Fisk S and W idom B 1969 J. Chem . Phys. 50 3219
- [39] Bu F P, Lovett R A and Stillinger F H 1965 Phys. Rev. Lett. 15 621
- [40] Mecke K R and Dietrich S 1999 Phys. Rev. E 59 6766
- [41] Thom son W T 1871 Philos. Mag. E 42 448
- [42] Bonn D and Ross D 2001 Rep. Prog. Phys. 64 1085
- [43] Bowers J, Zarbakhsh A, Querol A, Chistenson H K, McLur I A and Cubitt R 2004 J. Chem. Phys. 121 9058
- [44] Fisher M E and de Gennes 1978 C.R. Acad. Sci. Paris B 287 207
- [45] Schulz J, Bowers J and Findenegg G H 2001 J. Phys. Chem. B 105 6956